

isc N-Channel MOSFET Transistor

STB9NK90Z

FEATURES

- Drain Current : I_D= 8A@ T_C=25℃
- Drain Source Voltage
 - : V_{DSS}= 900V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 1.3 \Omega (Max) @ V_{GS} = 10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

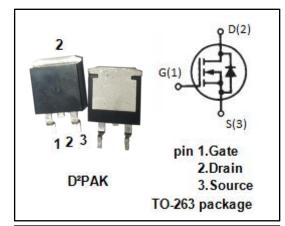
 motor drive, DC-DC converter, power switch and solenoid drive.

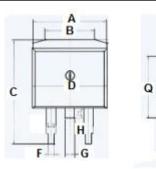
ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	900	V
V _{GSS}	Gate-Source Voltage	±30	V
I _D	Drain Current-Continuous;@Tc=25℃	8	А
I _{DM}	Drain Current-Single Pulsed	32	А
P _D	Total Dissipation	160	W
T _j	Operating Junction Temperature	-55~150	$^{\circ}$
T _{stg}	Storage Temperature	-55~150	$^{\circ}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.78	°C/W





DIM	m	ım
DIIVI	MIN	MAX
Α	9.8	10.2
В	6.6	6.8
С	15.1	15.3
D	9.6	10
F	0.7	0.9
G	1.26	1.3
Н	1.2	1.45
L	4.4	4.6
Q	9.2	9.3
S	1.25	1.35
V	0.4	0.6
W	2.6	2.8

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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	900	-	-	V
V _{GS(th)}	Gate Threshold Voltage	$V_{DS}=V_{GS}$; $I_{D}=0.1$ mA	3	-	4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =3.6A	-	-	1.3	Ω
I _{GSS}	Gate-Source Leakage Current	V_{GS} = $\pm 20V; V_{DS}$ = $0V$	-	-	±10	uA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 900V; V _{GS} = 0V	-	-	1	uA
V _{SD}	Diode forward voltage	I _{SD} = 8A, V _{GS} = 0 V	-	-	1.6	V

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